



## Discription

The ESD8D5.0C protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. Excellent clamping capability, low leakage, low capacitance, and fast response time provide best in class protection on designs that are exposed to ESD.

It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.



DFN1006-2L  
(SOD-882)

## Features

- ★ Low Leakage
- ★ Response Time is Typically < 1 ns
- ★ ESD Rating of Class 3 per Human Body Model
- ★ IEC61000-4-2 Level 4 ESD Protection
- ★ These are Pb-Free Devices
- ★ We declare that the material of product compliance with RoHS requirements and Halogen Free.



Circuit Diagram

## Ordering Information

| Product ID | Pack                | Qty(PCS) |
|------------|---------------------|----------|
| ESD8D5.0C  | DFN1006-2L(SOD-882) | 10000    |

## Absolute Ratings ( $T_{amb}=25^{\circ}\text{C}$ )

| Symbol    | Parameter                                         | Value                              | Units                      |
|-----------|---------------------------------------------------|------------------------------------|----------------------------|
| $P_{PP}$  | Peak Pulse Power ( $t_p = 8/20 \mu s$ )           | 90                                 | W                          |
| $T_L$     | Maximum lead temperature for soldering during 10s | 260                                | $^{\circ}\text{C}$         |
| $T_{stg}$ | Storage Temperature Range                         | -55 to +150                        | $^{\circ}\text{C}$         |
| $T_{op}$  | Operating Temperature Range                       | -55 to +150                        | $^{\circ}\text{C}$         |
| $T_j$     | Maximum junction temperature                      | 150                                | $^{\circ}\text{C}$         |
|           | IEC61000-4-2 (ESD)                                | air discharge<br>contact discharge | $\pm 25$<br>$\pm 20$<br>KV |



Electrical Characteristics

| Device    | $V_{RWM}$<br>(V) | $I_{R1}(\mu A)$<br>@ $V_{RWM}$ | $I_{R2}(\mu A)$<br>@ $V_R=3.5V$ | $V_{BR}$ (V) @ $I_T$<br>(Note 2) |     | $I_T$ | $V_C$ (V)<br>@ $I_{PP} = 1\text{ A}$<br>(Note 3) | $V_C$ (V)<br>@ MAX $I_{PP}$<br>(Note 3) | $I_{PP}(A)$<br>(Note 3) | $P_{PK}(W)$<br>(Note 3) | C (pF) |
|-----------|------------------|--------------------------------|---------------------------------|----------------------------------|-----|-------|--------------------------------------------------|-----------------------------------------|-------------------------|-------------------------|--------|
|           | Max              | Max                            | Max                             | Min                              | Max | mA    | Max                                              | Max                                     | Max                     | Max                     | Typ    |
| ESD8D5.0C | 5.0              | 0.5                            | 0.3                             | 5.6                              | 8.0 | 1.0   | 9.8                                              | 10                                      | 9                       | 90                      | 15     |

- Other voltage available upon request.
2.  $V_{BR}$  is measured with a pulse test current  $I_T$  at an ambient temperature of 25°C
3. Surge current waveform per Figure 3.

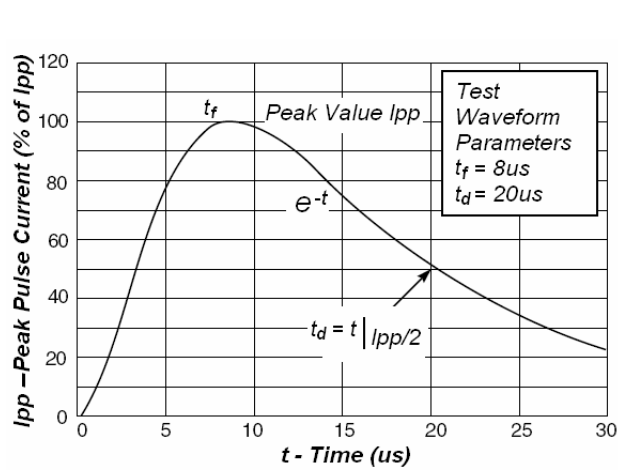


Fig1. Pulse Waveform

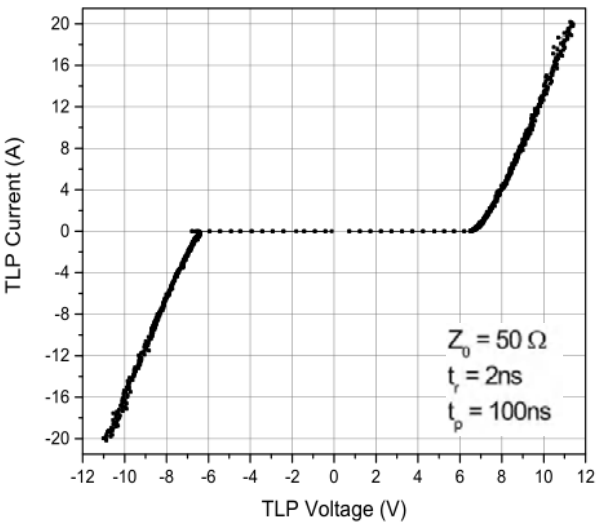
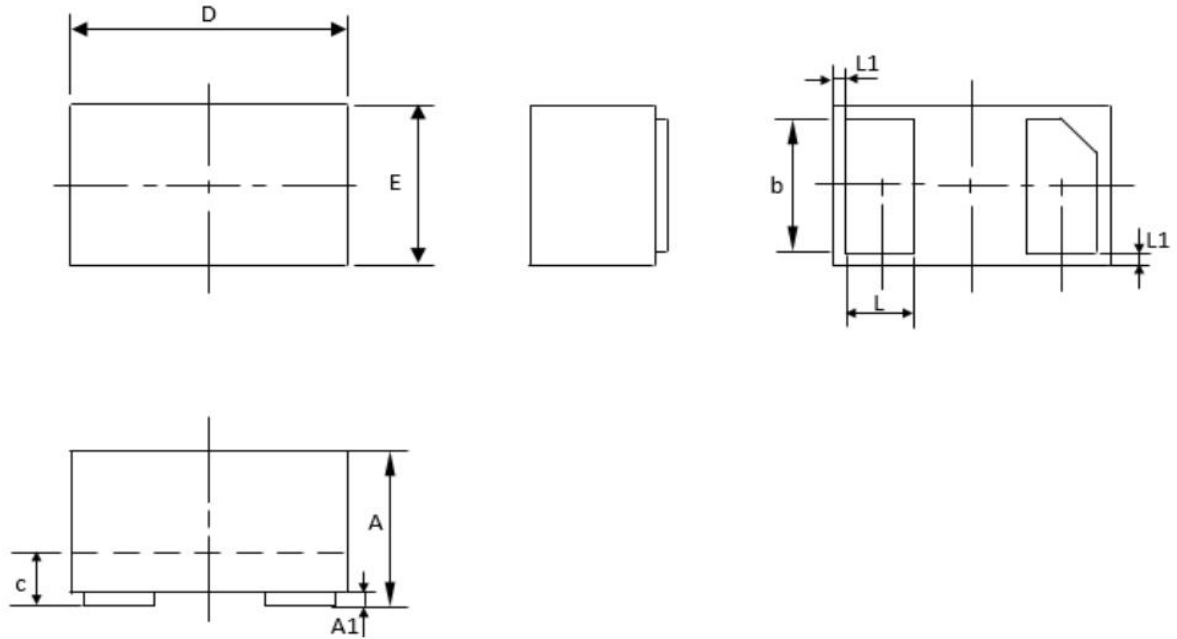


Fig2.TLP Measurement



## Outline And Dimensions



| DFN1006-2L(SOD-882)  |       |      |       |
|----------------------|-------|------|-------|
| Dim                  | Min   | Typ. | Max   |
| A                    | 0.46  | 0.48 | 0.50  |
| A1                   | 0     | 0.02 | 0.05  |
| b                    | 0.45  | 0.5  | 0.55  |
| c                    | 0.1   | 0.12 | 0.14  |
| D                    | 0.95  | 1.00 | 1.05  |
| E                    | 0.55  | 0.60 | 0.65  |
| L                    | 0.20  | 0.25 | 0.30  |
| L1                   | 0.035 | 0.05 | 0.065 |
| h                    | 0.07  | 0.12 | 0.17  |
| All Dimensions in mm |       |      |       |



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